

HD74LV1G66A

Analog Switch

REJ03D0069–0600Z
(Previous ADE-205-564D (Z))
Rev.6.00
Aug.29.2003

Description

The HD74LV1G66A has an analog switch in a 5 pin package. Switch section has its enable input control (C). High-level voltage applied to C turns on the switch section. Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog to digital and digital to analog conversion systems. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

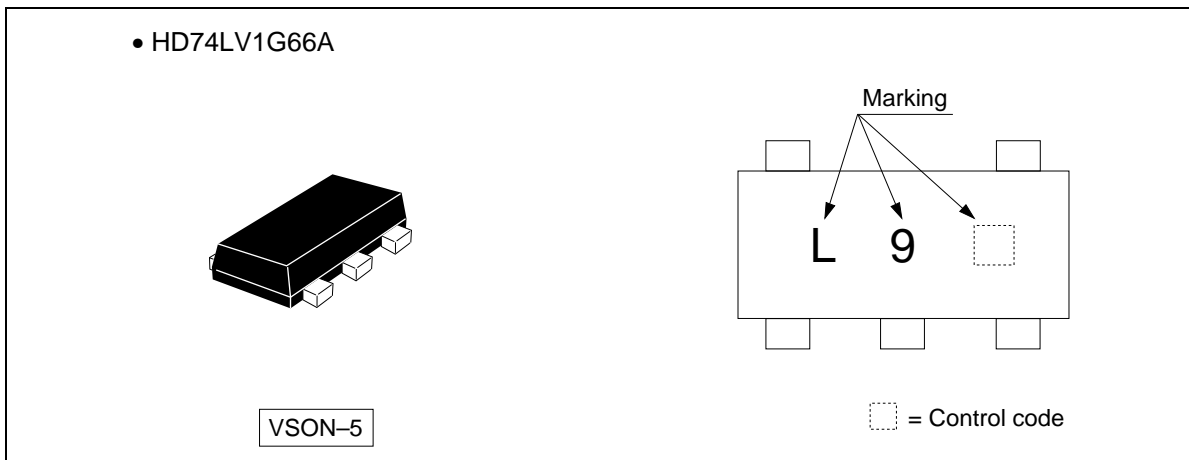
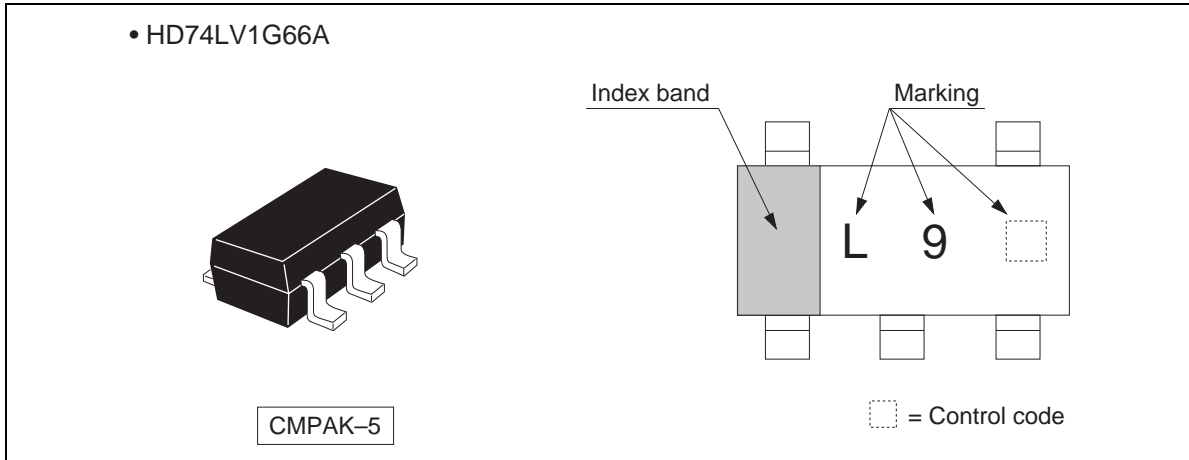
Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74LV4066A
Supply voltage range : 1.65 to 5.5 V
Operating temperature range : -40 to +85°C
- Control inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Control inputs has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1G66ACME	CMPAK-5 pin	CMPAK-5V	CM	E (3,000 pcs/reel)
		CMPAK-5V(O)		
HD74LV1G66AVSE	VSON-5 pin	TNP-5DV	VS	

Note: Please consult the sales office for the above package availability.

Outline and Article Indication



HD74LV1G66A

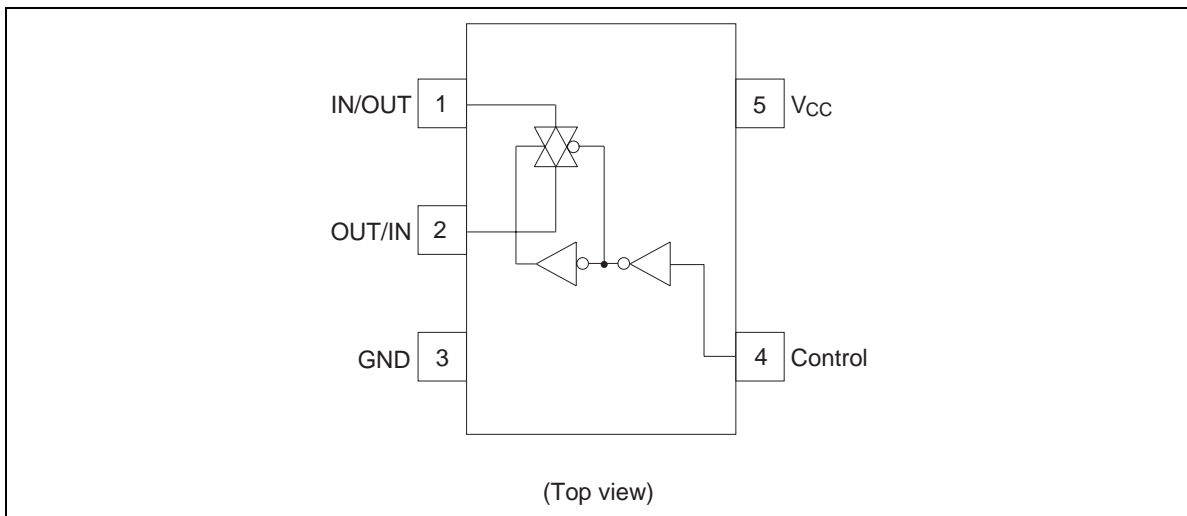
Function Table

Control	Switch
L	OFF
H	ON

H : High level

L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V_{CC}	-0.5 to 7.0	V	
Input voltage range ^{*1}	V_I	-0.5 to 7.0	V	
Output voltage range ^{*1, 2}	V_O	-0.5 to $V_{CC} + 0.5$	V	Output : H or L
Input clamp current	I_{IK}	-20	mA	$V_I < 0$
Output clamp current	I_{OK}	± 50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	± 25	mA	$V_O = 0$ to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	± 50	mA	
Maximum power dissipation at $T_a = 25^\circ\text{C}$ (in still air) ^{*3}	P_T	200	mW	
Storage temperature	T_{stg}	-65 to 150	$^\circ\text{C}$	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The maximum package power dissipation was calculated using a junction temperature of 150 $^\circ\text{C}$.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	1.65	5.5	V	
Input voltage range	V_I	0	5.5	V	
Input / output voltage range	V_{IO}	0	V_{CC}	V	
Input transition rise or fall rate	$\Delta t / \Delta v$	0	300	ns / V	$V_{CC} = 1.65$ to 1.95 V
		0	200		$V_{CC} = 2.3$ to 2.7 V
		0	100		$V_{CC} = 3.0$ to 3.6 V
		0	20		$V_{CC} = 4.5$ to 5.5 V
Operating free-air temperature	T_a	-40	85	$^\circ\text{C}$	

Note: Unused or floating control inputs must be held high or low.

Electrical Characteristics

Item	Symbol	V _{CC} (V)	T _a = 25°C			T _a = -40 to 85°C			Unit	Test Conditions
			Min	Typ	Max	Min	Typ	Max		
Input voltage	V _{IH}	1.65 to 1.95	—	—	—	V _{CC} ×0.75	—	—	V	Control input only
		2.3 to 2.7	—	—	—	V _{CC} ×0.7	—	—		
		3.0 to 3.6	—	—	—	V _{CC} ×0.7	—	—		
		4.5 to 5.5	—	—	—	V _{CC} ×0.7	—	—		
	V _{IL}	1.65 to 1.95	—	—	—	—	—	V _{CC} ×0.25		
		2.3 to 2.7	—	—	—	—	—	V _{CC} ×0.3		
		3.0 to 3.6	—	—	—	—	—	V _{CC} ×0.3		
		4.5 to 5.5	—	—	—	—	—	V _{CC} ×0.3		
Hysteresis voltage	V _H	1.8	—	—	—	—	0.25	—	V	V _T ⁺ - V _T ⁻
		2.5	—	—	—	—	0.30	—		
		3.3	—	—	—	—	0.35	—		
		5.0	—	—	—	—	0.45	—		
On-state switch resistance	R _{ON}	1.65	—	120	360	—	—	450	Ω	V _{IN} = V _{CC} or GND V _C = V _{IH} I _T = 1 mA
		2.3	—	60	180	—	—	225		
		3.0	—	50	150	—	—	190		
		4.5	—	40	75	—	—	100		
Peak on resistance	R _{ON(P)}	1.65	—	700	1100	—	—	1400	Ω	V _{IN} = V _{CC} to GND V _C = V _{IH} I _T = 1 mA
		2.3	—	250	500	—	—	600		
		3.0	—	100	180	—	—	225		
		4.5	—	50	100	—	—	125		
Off-state switch leakage current	I _{s(OFF)}	5.5	—	—	±0.1	—	—	±1.0	μA	V _{IN} = V _{CC} , V _{OUT} = GND or V _{IN} = GND, V _O = V _{CC} , V _C = V _{IL}
On-state switch leakage current	I _{s(ON)}	5.5	—	—	±0.1	—	—	±1.0	μA	V _{IN} = V _{CC} or GND V _C = V _{IH}
Input current	I _{IN}	0 to 5.5	—	—	±0.1	—	—	±1.0	μA	V _{IN} = 5.5 V or GND
Quiescent supply current	I _{CC}	5.5	—	—	—	—	—	10	μA	V _{IN} = V _{CC} or GND
Control input capacitance	C _{IC}	—	—	3.5	—	—	—	—	pF	
Switch terminal capacitance	C _{IN/OUT}	—	—	4.0	—	—	—	—	pF	
Feed through capacitance	C _{IN-OUT}	—	—	0.5	—	—	—	—	pF	

Switching Characteristics

- $V_{CC} = 1.8 \pm 0.15 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Propagation delay time	t _{PLH}	—	4.0	13.0	—	19.0	ns	C _L = 15 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
	t _{PHL}	—	11.0	23.0	—	29.0		C _L = 50 pF		
Enable time	t _{ZH}	—	11.0	24.0	—	29.0	ns	C _L = 15 pF	C	IN/OUT or OUT/IN
	t _{ZL}	—	18.0	44.0	—	51.0		C _L = 50 pF		
Disable time	t _{HZ}	—	11.0	21.0	—	29.0	ns	C _L = 15 pF	C	IN/OUT or OUT/IN
	t _{LZ}	—	18.0	46.0	—	53.0		C _L = 50 pF		

- $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Propagation delay time	t _{PLH}	—	2.0	10.0	—	16.0	ns	C _L = 15 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
	t _{PHL}	—	5.0	12.0	—	18.0		C _L = 50 pF		
Enable time	t _{ZH}	—	6.0	15.0	—	20.0	ns	C _L = 15 pF	C	IN/OUT or OUT/IN
	t _{ZL}	—	8.0	25.0	—	32.0		C _L = 50 pF		
Disable time	t _{HZ}	—	7.0	15.0	—	23.0	ns	C _L = 15 pF	C	IN/OUT or OUT/IN
	t _{LZ}	—	11.0	25.0	—	32.0		C _L = 50 pF		

- $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Propagation delay time	t _{PLH}	—	1.5	6.0	—	10.0	ns	C _L = 15 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
	t _{PHL}	—	4.0	9.0	—	12.0		C _L = 50 pF		
Enable time	t _{ZH}	—	4.0	11.0	—	15.0	ns	C _L = 15 pF	C	IN/OUT or OUT/IN
	t _{ZL}	—	6.0	18.0	—	22.0		C _L = 50 pF		
Disable time	t _{HZ}	—	5.0	11.0	—	15.0	ns	C _L = 15 pF	C	IN/OUT or OUT/IN
	t _{LZ}	—	8.0	18.0	—	22.0		C _L = 50 pF		

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Switching Characteristics (cont)

- $V_{CC} = 5.0 \pm 0.5$ V

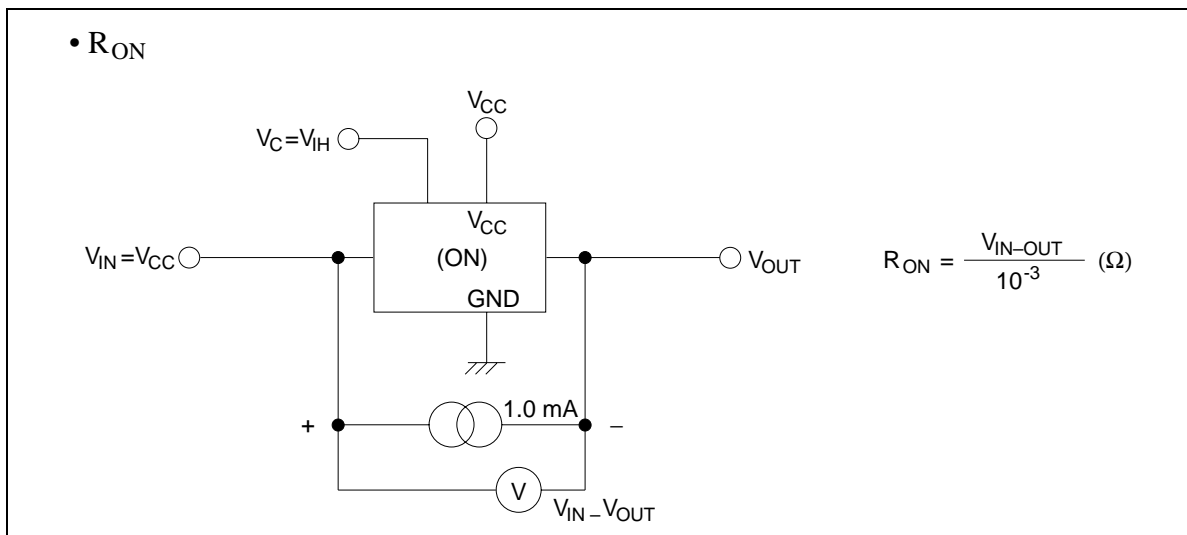
Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Propagation delay time	t_{PLH}	—	1.0	4.0	—	7.0	ns	$C_L = 15$ pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
	t_{PHL}	—	3.0	6.0	—	8.0		$C_L = 50$ pF		
Enable time	t_{ZH}	—	3.0	7.0	—	10.0	ns	$C_L = 15$ pF	C	IN/OUT or OUT/IN
	t_{ZL}	—	5.0	12.0	—	16.0		$C_L = 50$ pF		
Disable time	t_{HZ}	—	4.0	7.0	—	10.0	ns	$C_L = 15$ pF	C	IN/OUT or OUT/IN
	t_{LZ}	—	6.0	12.0	—	16.0		$C_L = 50$ pF		

Operating Characteristics

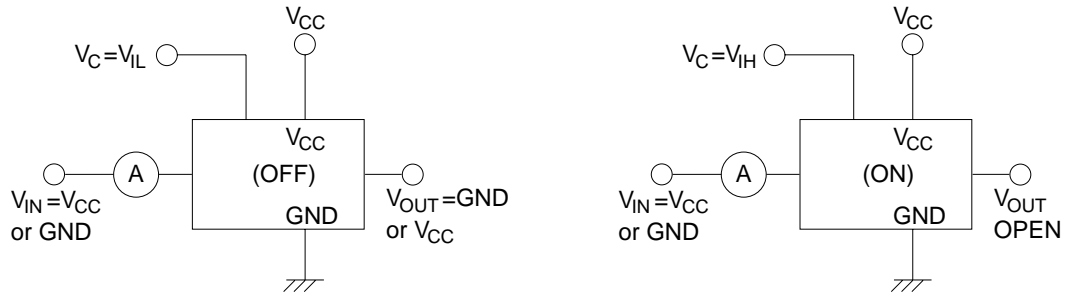
- $C_L = 50$ pF

Item	Symbol	V _{CC} (V)	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C _{PD}	3.3	—	3.5	—	pF	f = 10 MHz
		5.0	—	4.0	—		

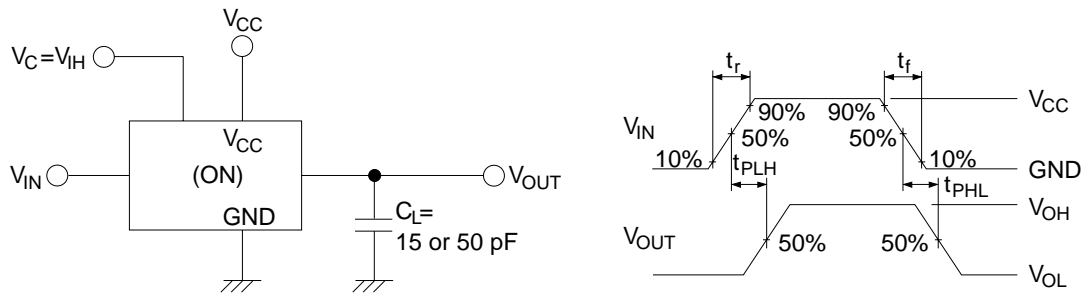
Test Circuit



• I_S (off), I_S (on)

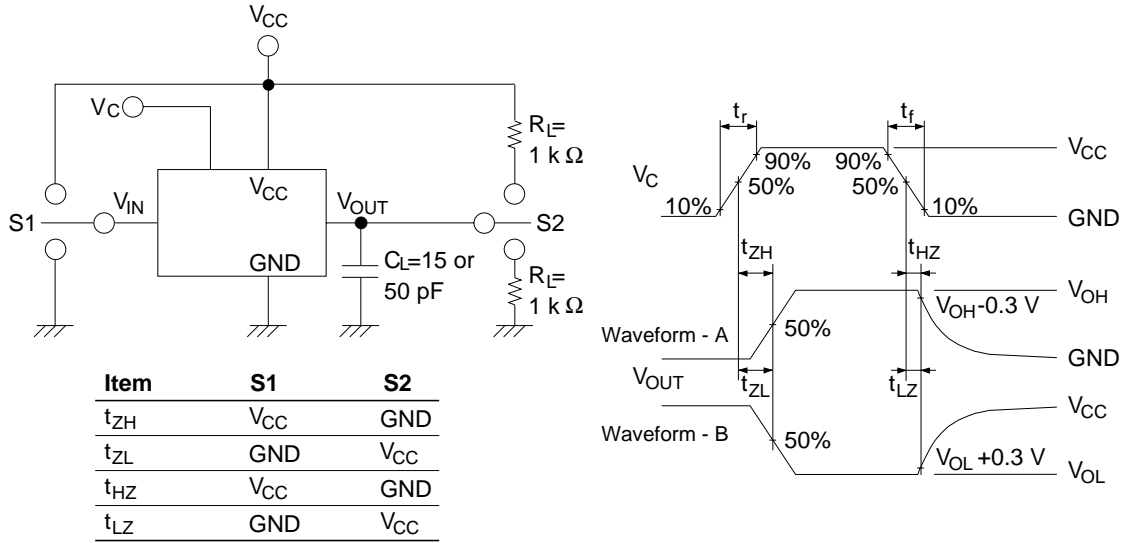


• t_{PLH} , t_{PHL}



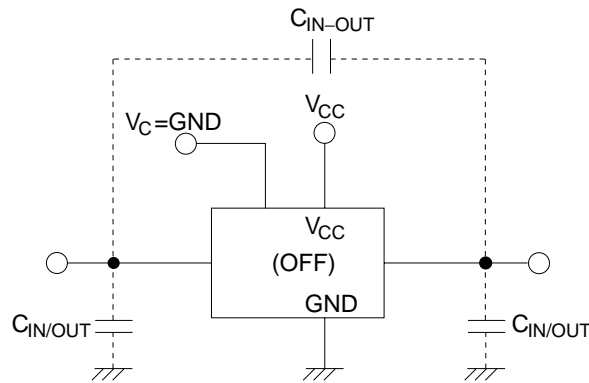
- Notes: 1. Input waveform : $PRR \leq 1$ MHz, $Z_o = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
 2. The output are measured one at a time with one transition per measurement.

• $t_{ZH}, t_{ZL} / t_{HZ}, t_{LZ}$

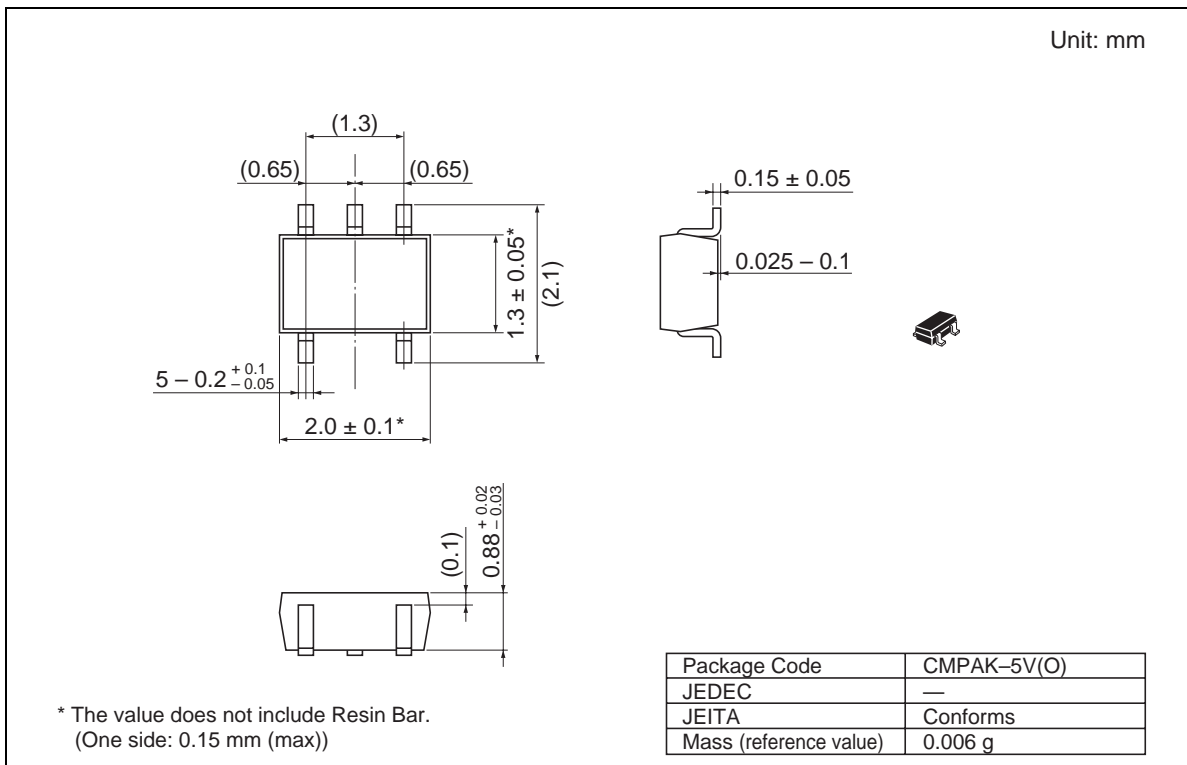
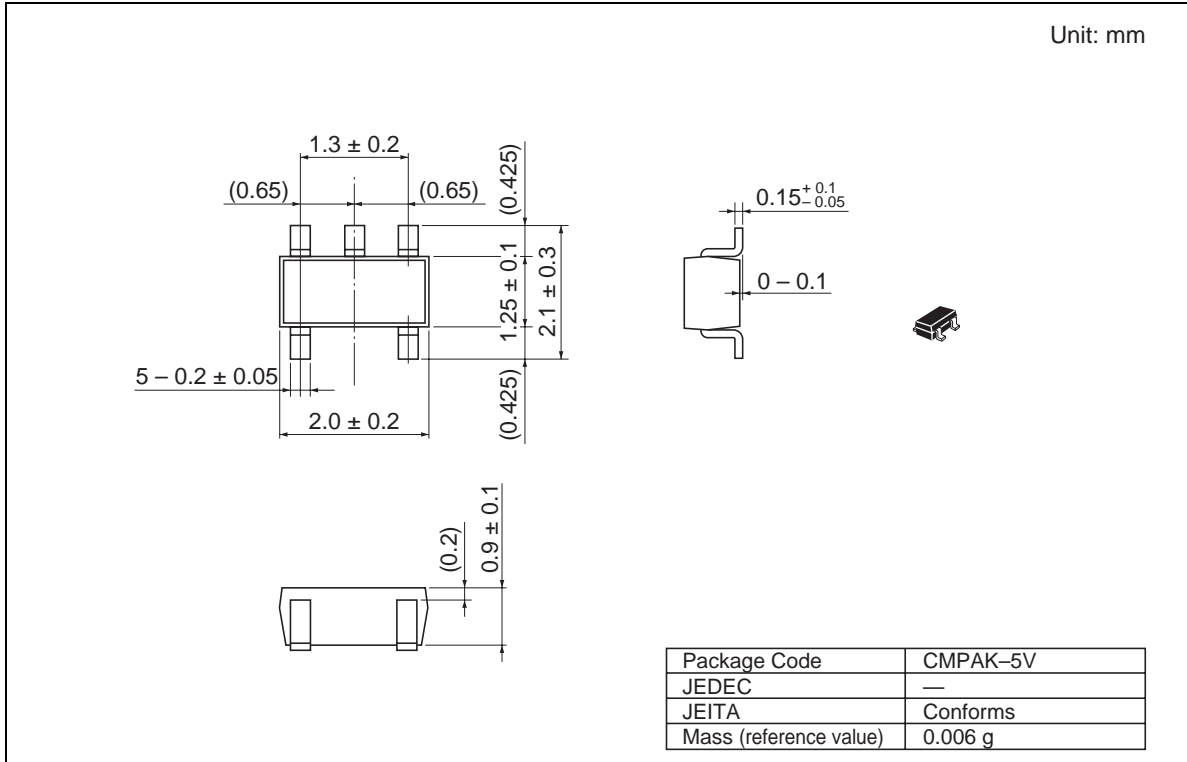


- Notes:
1. Input waveform : PRR \leq 1 MHz, $Z_o = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
 2. Waveform - A is for an output with internal conditions such that the output is high except when disabled by the output control.
 3. Waveform - B is for an output with internal conditions such that the output is low except when disabled by the output control.
 4. The output are measured one at a time with one transition per measurement.

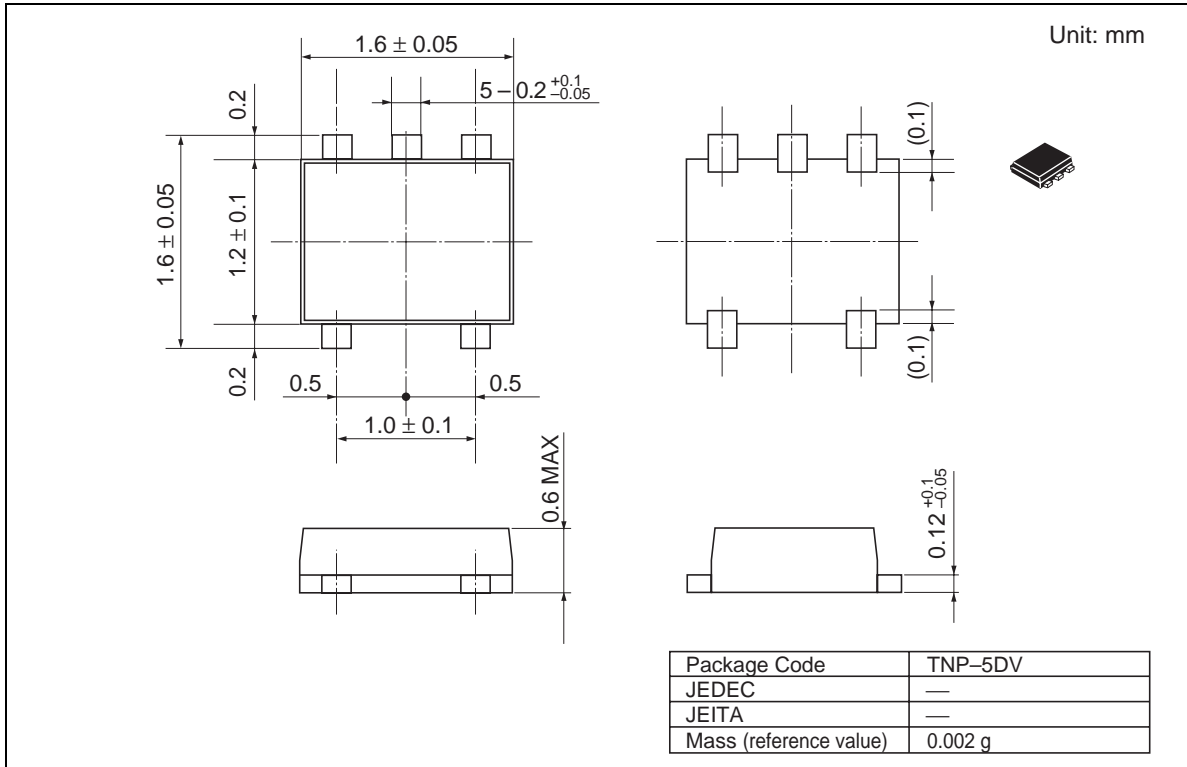
• $C_{IN/OUT}, C_{IN-OUT}$



Package Dimensions



HD74LV1G66A



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